RENESAS

RJK03E6DPA

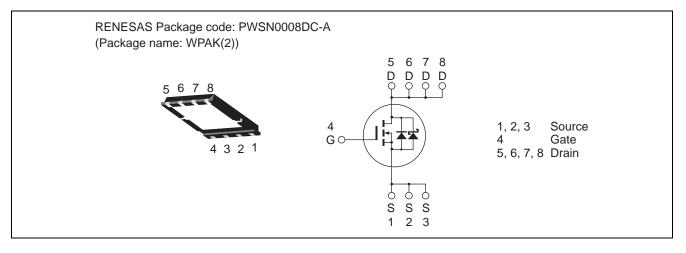
Silicon N Channel Power MOS FET with Schottky Barrier Diode Power Switching REJ03G1930-0210 Rev 2 10

Rev.2.10 May 20, 2010

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance $R_{DS(on)} = 3.8 \text{ m}\Omega \text{ typ.} (at V_{GS} = 8 \text{ V})$
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

| | | | $(Ta = 25^{\circ}C)$ | |
|--|--------------------------------|-------------|----------------------|--|
| ltem | Symbol | Ratings | Unit | |
| Drain to source voltage | V _{DSS} | 30 | V | |
| Gate to source voltage | V _{GSS} | ±12 | V | |
| Drain current | I _D | 35 | А | |
| Drain peak current | Note1 I _{D(pulse)} | 140 | А | |
| Body-drain diode reverse drain current | I _{DR} | 35 | А | |
| Avalanche current | I _{AP} Note 2 | 13 | А | |
| Avalanche energy | E _{AR} Note 2 | 16.9 | mJ | |
| Channel dissipation | Pch Note3 | 35 | W | |
| Channel to case thermal impedance | θch-c ^{Note3} | 3.57 | °C/W | |
| Channel temperature | Tch | 150 | ٥C | |
| Storage temperature | Tstg | -55 to +150 | ٥C | |
| | | | | |

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tch = 25°C, Rg \ge 50 Ω

3. Tc = 25°C



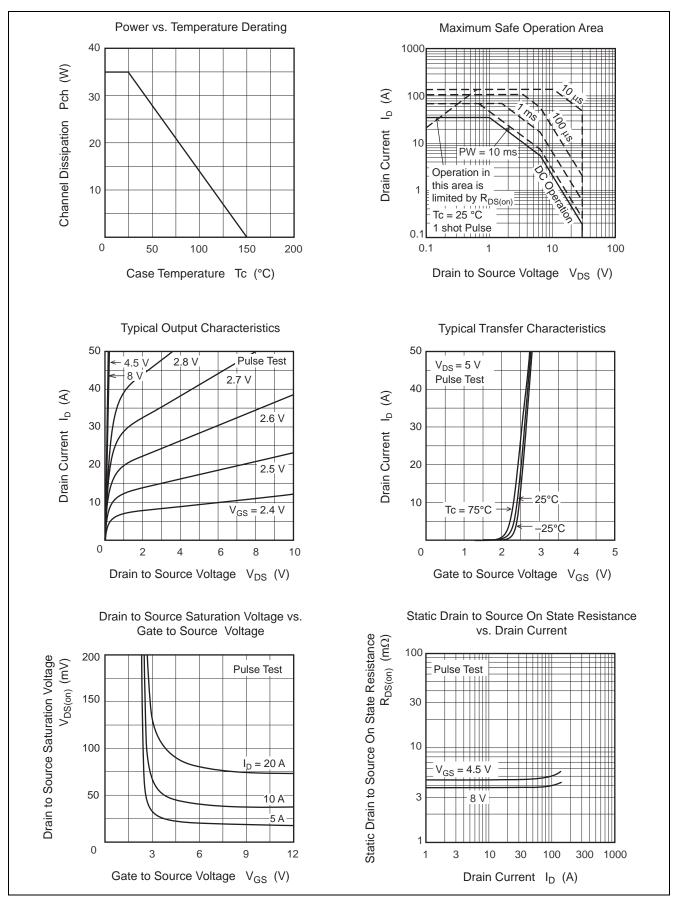
Electrical Characteristics

| | | | | | | $(Ta = 25^{\circ}C)$ |
|-----------------------------------|----------------------|-----|------|-------|------|--|
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
| Drain to source breakdown voltage | V _{(BR)DSS} | 30 | — | — | V | $I_D = 10 \text{ mA}, V_{GS} = 0$ |
| Gate to source leak current | I _{GSS} | _ | — | ± 0.1 | μΑ | $V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | — | 1 | mA | $V_{DS} = 30 V, V_{GS} = 0$ |
| Gate to source cutoff voltage | V _{GS(off)} | 1.2 | _ | 2.5 | V | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$ |
| Static drain to source on state | R _{DS(on)} | _ | 3.8 | 4.6 | mΩ | $I_D = 17.5A, V_{GS} = 8.0 V^{Note4}$ |
| resistance | R _{DS(on)} | _ | 4.6 | 5.6 | mΩ | $I_D = 17.5A, V_{GS} = 4.5 V^{Note4}$ |
| Forward transfer admittance | y _{fs} | | 83 | _ | S | $I_D = 17.5A, V_{DS} = 5 V^{Note4}$ |
| Input capacitance | Ciss | | 2670 | 3740 | pF | V _{DS} = 10 V |
| Output capacitance | Coss | | 320 | _ | pF | V _{GS} = 0 f = 1 MHz |
| Reverse transfer capacitance | Crss | | 200 | _ | pF | |
| Gate Resistance | Rg | | 1.7 | 3.4 | Ω | |
| Total gate charge | Qg | | 20 | | nC | V _{DD} = 10 V |
| Gate to source charge | Qgs | | 7 | _ | nC | V _{GS} = 4.5 V I _D = 35 A |
| Gate to drain charge | Qgd | | 6.2 | | nC | |
| Turn-on delay time | t _{d(on)} | | 14 | | ns | V _{GS} = 8 V, I _D =17.5 A |
| Rise time | tr | | 5.4 | | ns | $V_{DD} \cong 10 \text{ V}$ $R_{L} = 0.57\Omega$ $Rg = 4.7 \Omega$ |
| Turn-off delay time | t _{d(off)} | | 52 | _ | ns | |
| Fall time | t _f | | 8 | | ns | |
| Body–drain diode forward voltage | V _{DF} | _ | 0.39 | | V | $I_F = 2 \text{ A}, V_{GS} = 0^{Note4}$ |
| Body-drain diode reverse recovery | t _{rr} | | 24 | | ns | $I_F = 35 \text{ A}, V_{GS} = 0$ |
| time | | | | | | $di_F/dt = 100 \text{ A}/\mu \text{s}$ |

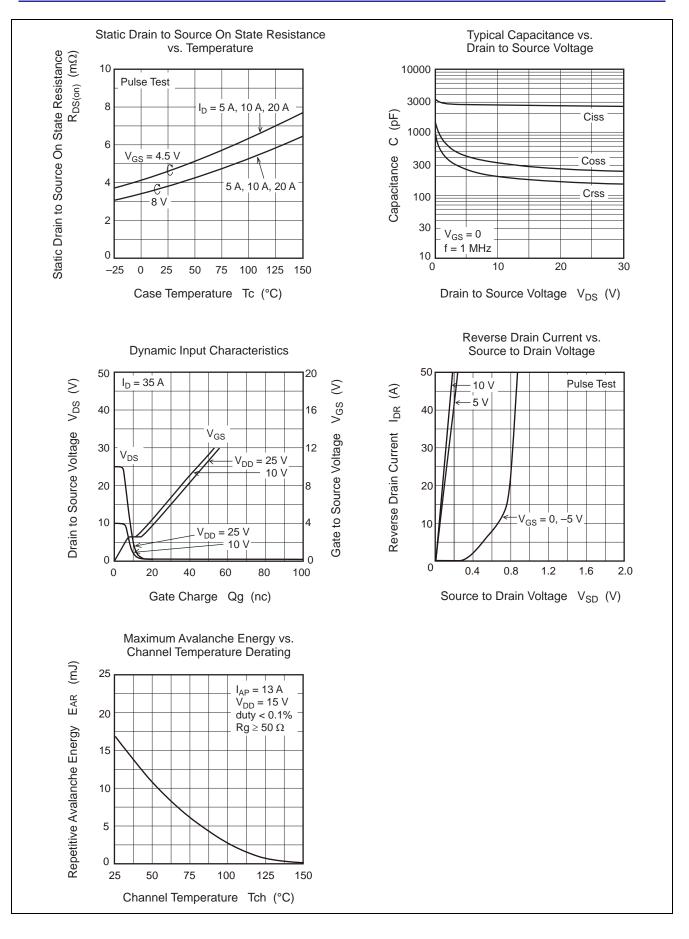
Notes: 4. Pulse test



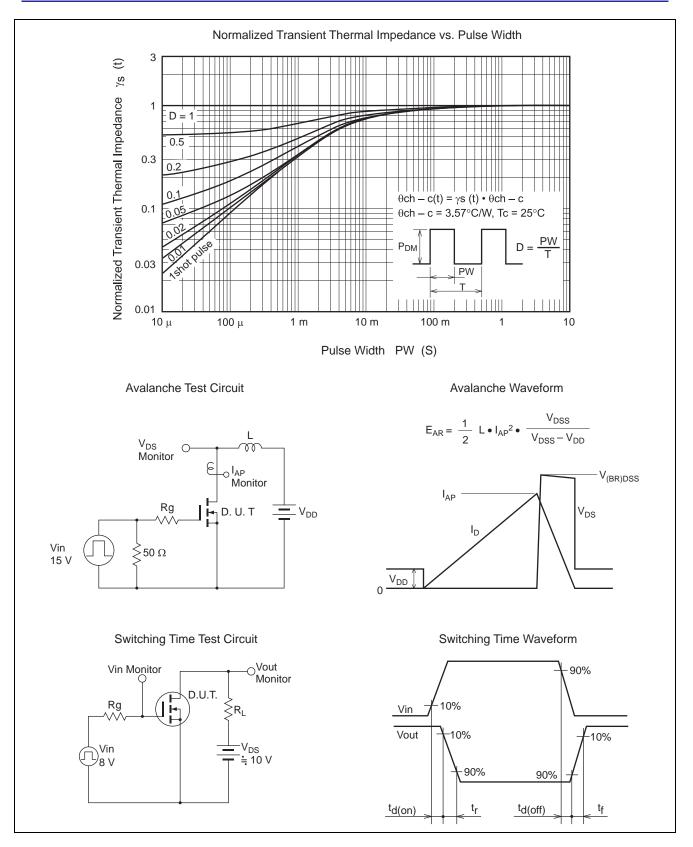
Main Characteristics





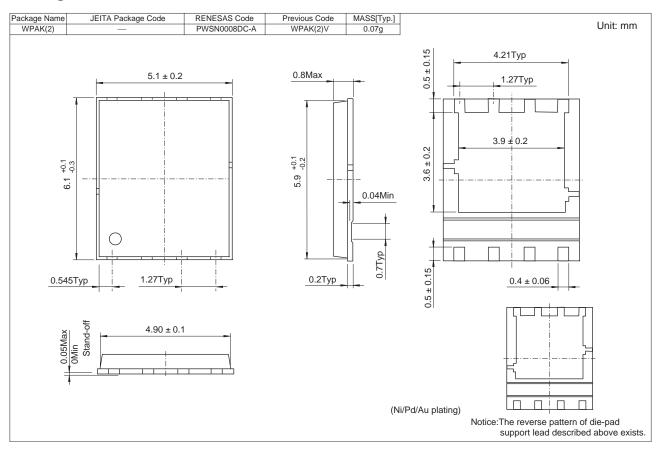








Package Dimensions



Ordering Information

| Part No. | Quantity | Shipping Container |
|-------------------|----------|--------------------|
| RJK03E6DPA-00-J53 | 3000 pcs | Taping |



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